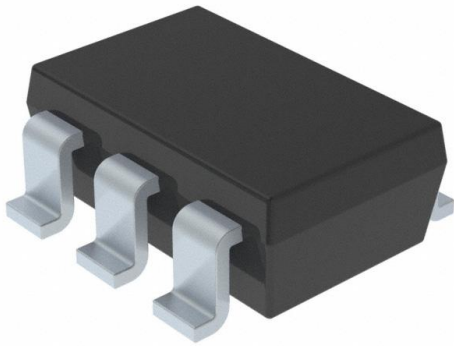


DDA114YK-7-F Datasheet

www.digi-electronics.com



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	DDA114YK-7-F-DG
Manufacturer	Diodes Incorporated
Manufacturer Product Number	DDA114YK-7-F
Description	TRANS PREBIAS DUAL PNP SOT26
Detailed Description	Pre-Biased Bipolar Transistor (BJT) 2 PNP - Pre-Biased (Dual) 50V 100mA 250MHz 300mW Surface Mount SOT-26



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

DiGi is a global authorized distributor of electronic components.

Purchase and inquiry

Manufacturer Product Number:

DDA114YK-7-F

Series:

-

Transistor Type:

2 PNP - Pre-Biased (Dual)

Voltage - Collector Emitter Breakdown (Max):

50V

Resistor - Emitter Base (R2):

47kOhms

Vce Saturation (Max) @ Ib, Ic:

300mV @ 250µA, 5mA

Frequency - Transition:

250MHz

Mounting Type:

Surface Mount

Supplier Device Package:

SOT-26

Manufacturer:

Diodes Incorporated

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100mA

Resistor - Base (R1):

10kOhms

DC Current Gain (hFE) (Min) @ Ic, Vce:

68 @ 10mA, 5V

Current - Collector Cutoff (Max):

-

Power - Max:

300mW

Package / Case:

SOT-23-6

Base Product Number:

DDA114

Environmental & Export classification

RoHS Status:

ROHS3 Compliant

REACH Status:

REACH Unaffected

HTSUS:

8541.21.0075

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

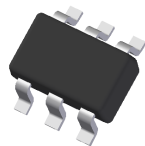
EAR99

PNP PRE-BIASED SMALL SIGNAL DUAL SURFACE MOUNT TRANSISTOR

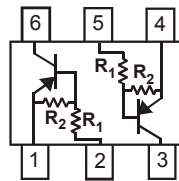
Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDC)
- Built-In Biasing Resistors
- Available in Lead Free/RoHS Compliant Version (Note 3)

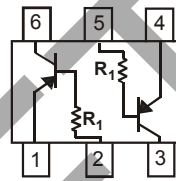
Part Number	R1	R2	Marking
DDA124EK	22K Ω	22K Ω	P17
DDA144EK	47K Ω	47K Ω	P20
DDA114YK	10K Ω	47K Ω	P14
DDA123JK	2.2K Ω	47K Ω	P06
DDA114EK	10K Ω	10K Ω	P13
DDA143TK	4.7K Ω	-	P07
DDA114TK	10K Ω	-	P12



Top View



R1, R2 Device Schematic



R1 only Device Schematic

Mechanical Data

- Case: SOT-26
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Also Available in Lead Free Plating (Matte Tin Finish annealed over Copper leadframe). Please see Ordering Information, Note 5, on Page 5
- Marking Information: See Table and Page 5
- Ordering Information See Page 5
- Weight: 0.015 grams (approximate)

Maximum Ratings @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage, (1) to (6) and (4) to (3)	V_{CC}	50	V
Input Voltage, (2) to (1) and (5) to (4)	V_{IN}	DDA124EK +10 to -40 DDA144EK +10 to -40 DDA114YK +6 to -40 DDA123JK +5 to -12 DDA114EK +10 to -40 DDA143TK +5V max DDA114TK +5V max	V
Output Current	I_O	DDA124EK -30 DDA144EK -30 DDA114YK -70 DDA123JK -100 DDA114EK -50 DDA143TK -100 DDA114TK -100	mA
Output Current	$I_{C(MAX)}$	All -100	mA

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Total)	P_D	300	mW
Thermal Resistance, Junction to Ambient Air (Note 1)	$R_{\theta JA}$	416.7	$^\circ\text{C/W}$
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

- Notes:
1. Mounted on FR4 PC Board with recommended pad layout at <http://www.diodes.com/datasheets/ap02001.pdf>.
 2. 200mW per element must not be exceeded.
 3. No purposefully added lead.

Electrical Characteristics @ $T_A = 25^\circ\text{C}$ unless otherwise specified

Characteristic (DDA143TK & DDA114TK only)	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV_{CBO}	-50	—	—	V	$I_C = -50\mu\text{A}$
Collector-Emitter Breakdown Voltage	BV_{CEO}	-50	—	—	V	$I_C = -1\text{mA}$
Emitter-Base Breakdown Voltage	BV_{EBO}	-5	—	—	V	$I_E = -50\mu\text{A}$
Collector Cutoff Current	I_{CBO}	—	—	-0.5	μA	$V_{CB} = -50\text{V}$
Emitter Cutoff Current	I_{EBO}	—	—	-0.5	μA	$V_{EB} = -4\text{V}$
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$	—	—	-0.3	V	$I_C/I_B = -2.5\text{mA} / -0.25\text{mA}$ DDA143TK $I_C/I_B = -1\text{mA} / -0.1\text{mA}$ DDA114TK
DC Current Transfer Ratio	h_{FE}	100	250	600	—	$I_C = -1\text{mA}$, $V_{CE} = -5\text{V}$
Input Resistor (R_1) Tolerance	ΔR_1	-30	—	+30	%	—
Gain-Bandwidth Product*	f_T	—	250	—	MHz	$V_{CE} = -10\text{V}$, $I_E = 5\text{mA}$, $f = 100\text{MHz}$

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	$V_{I(OFF)}$	-0.5	-1.1	—	V	$V_{CC} = -5\text{V}$, $I_O = -100\mu\text{A}$
		-0.5	-1.1	—		
Input Voltage	$V_{I(ON)}$	-0.3	—	—	V	$V_O = -0.3$, $I_O = -5\text{mA}$
		-0.5	—	—		
Input Voltage	$V_{I(ON)}$	-0.5	—	—	V	$V_O = -0.3$, $I_O = -2\text{mA}$
		-0.5	—	—		
Output Voltage	$V_{O(ON)}$	—	-1.9	-3.0	V	$V_O = -0.3$, $I_O = -1\text{mA}$
		—	-1.9	-3.0		
Output Voltage	$V_{O(ON)}$	—	—	-1.4	V	$V_O = -0.3$, $I_O = -5\text{mA}$
		—	—	-1.1		
Output Voltage	$V_{O(ON)}$	—	-1.9	-3.0	V	$V_O = -0.3$, $I_O = -10\text{mA}$
		—	-1.9	-3.0		
Output Voltage	$V_{O(ON)}$	—	-0.1	-0.3	V	$I_O/I_I = -10\text{mA} / -0.5\text{mA}$
		—	-0.1	-0.3		
Output Voltage	$V_{O(ON)}$	—	-0.1	-0.3	V	$I_O/I_I = -10\text{mA} / -0.5\text{mA}$
		—	-0.1	-0.3		
Output Voltage	$V_{O(ON)}$	—	-0.1	-0.3	V	$I_O/I_I = -5\text{mA} / -0.25\text{mA}$
		—	-0.1	-0.3		
Output Voltage	$V_{O(ON)}$	—	-0.1	-0.3	V	$I_O/I_I = -5\text{mA} / -0.25\text{mA}$
		—	-0.1	-0.3		
Input Current	I_I	—	—	-0.36	mA	$V_I = -5\text{V}$
		—	—	-0.18		
Input Current	I_I	—	—	-0.88	mA	$V_I = -5\text{V}$
		—	—	-3.6		
Input Current	I_I	—	—	-0.88	mA	$V_I = -5\text{V}$
		—	—	-0.88		
Output Current	$I_{O(OFF)}$	—	—	-0.5	μA	$V_{CC} = 50\text{V}$, $V_I = 0\text{V}$
DC Current Gain	G_I	56	—	—	—	$V_O = -5\text{V}$, $I_O = -5\text{mA}$
		68	—	—		
DC Current Gain	G_I	68	—	—	—	$V_O = -5\text{V}$, $I_O = -5\text{mA}$
		68	—	—		
DC Current Gain	G_I	80	—	—	—	$V_O = -5\text{V}$, $I_O = -10\text{mA}$
		80	—	—		
DC Current Gain	G_I	30	—	—	—	$V_O = -5\text{V}$, $I_O = -10\text{mA}$
		30	—	—		
DC Current Gain	G_I	—	—	—	—	$V_O = -5\text{V}$, $I_O = -5\text{mA}$
Input Resistor (R_1) Tolerance	ΔR_1	-30	—	+30	%	—
Resistance Ratio Tolerance	R_2/R_1	-20	—	+20	%	—
Gain-Bandwidth Product*	f_T	—	250	—	MHz	$V_{CE} = -10\text{V}$, $I_E = -5\text{mA}$, $f = 100\text{MHz}$

* Transistor - For Reference Only

OBSOLETE - PART DISCONTINUED

Typical Curves – DDA123JK One Section

OBSOLETE – PART DISCONTINUED

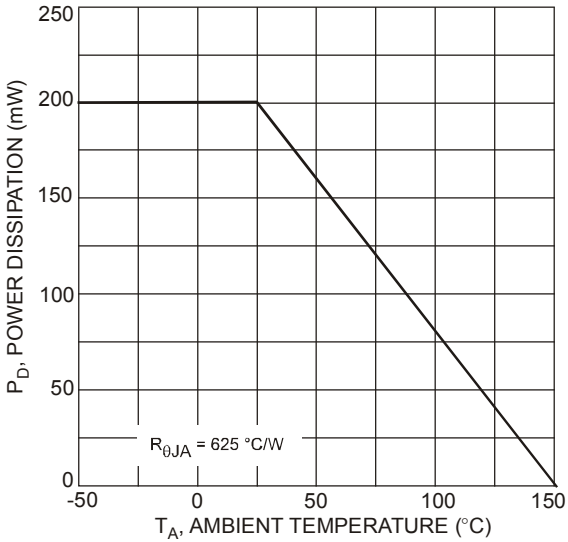


Fig. 1 Power Dissipation vs. Ambient Temperature

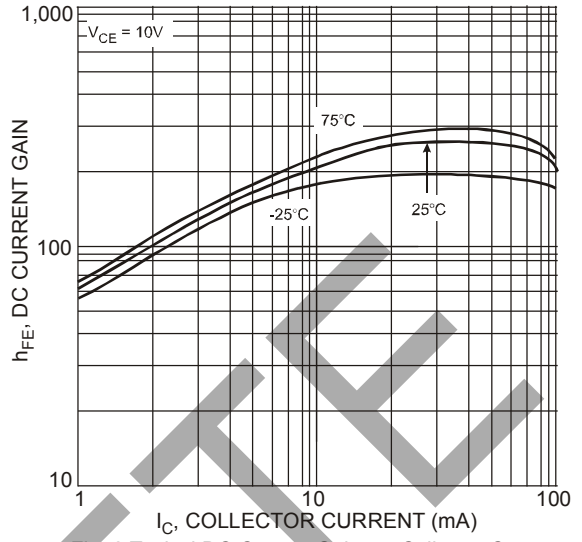


Fig. 2 Typical DC Current Gain vs. Collector Current

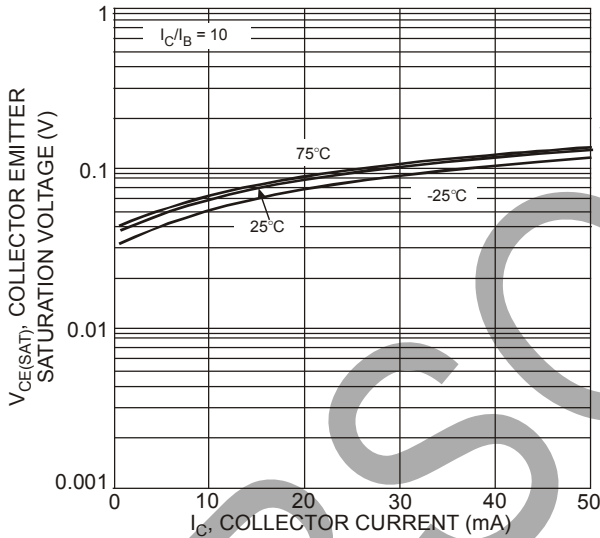


Fig. 3 Typical Collector Emitter Saturation Voltage vs. Collector Current

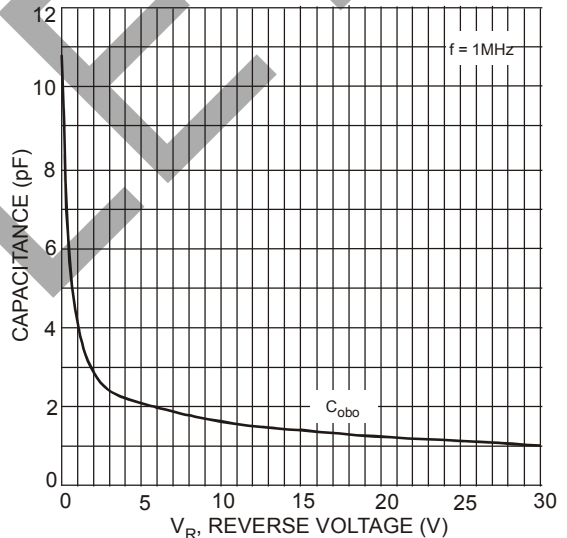


Fig. 4 Typical Capacitance Characteristics

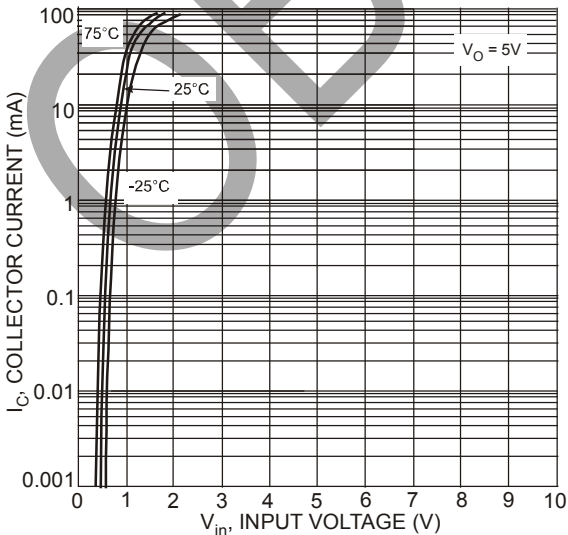


Fig. 5 Collector Current vs. Input Voltage

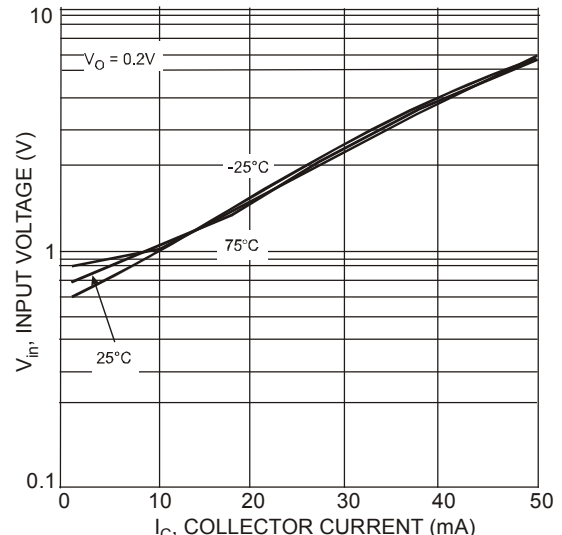


Fig. 6 Input Voltage vs. Collector Current

Typical Curves – DDA1414TK One Section

OBSOLETE – PART DISCONTINUED

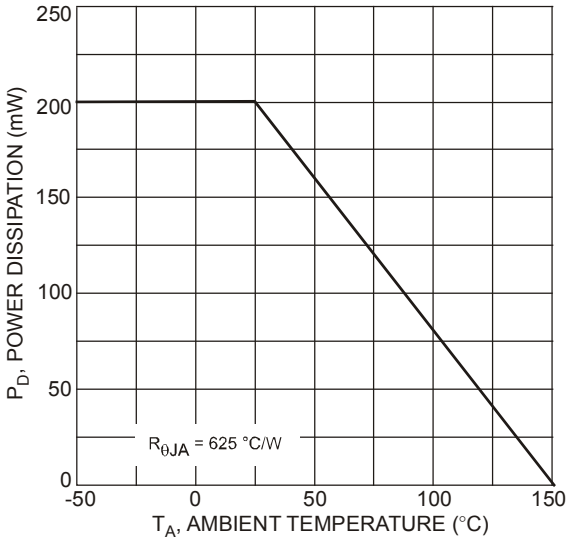


Fig. 1 Power Dissipation vs. Ambient Temperature

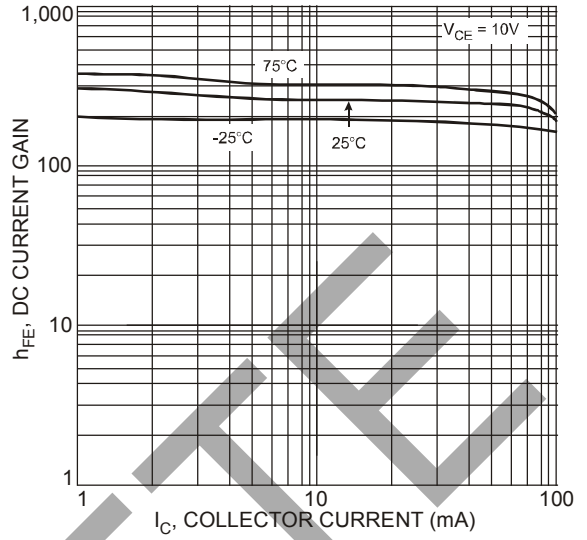


Fig. 2 Typical DC Current Gain vs. Collector Current

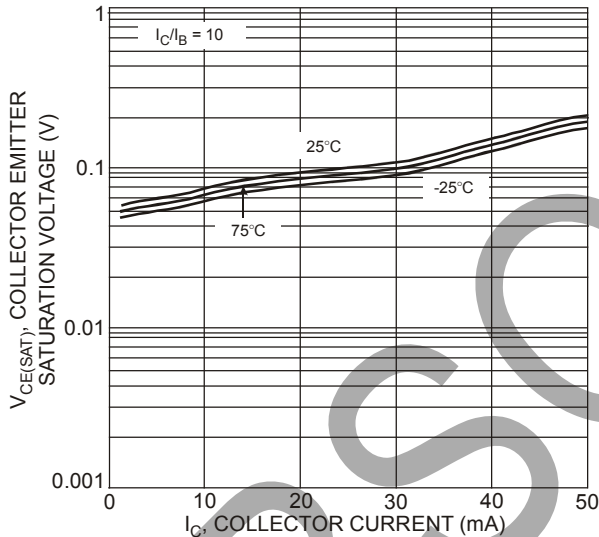


Fig. 3 Typical Collector Emitter Saturation Voltage vs. Collector Current

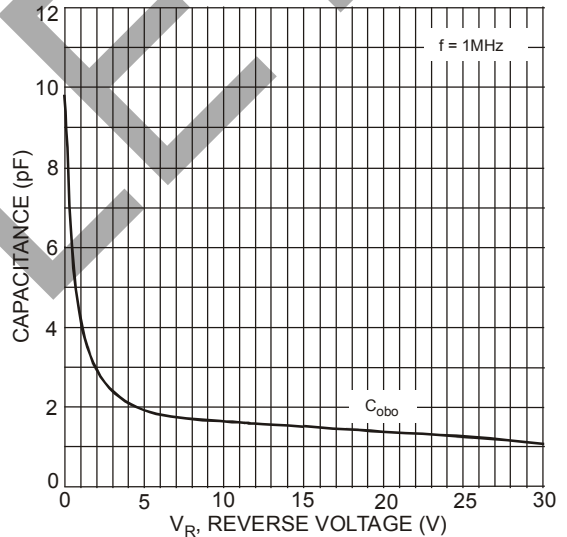


Fig. 4 Typical Capacitance Characteristics

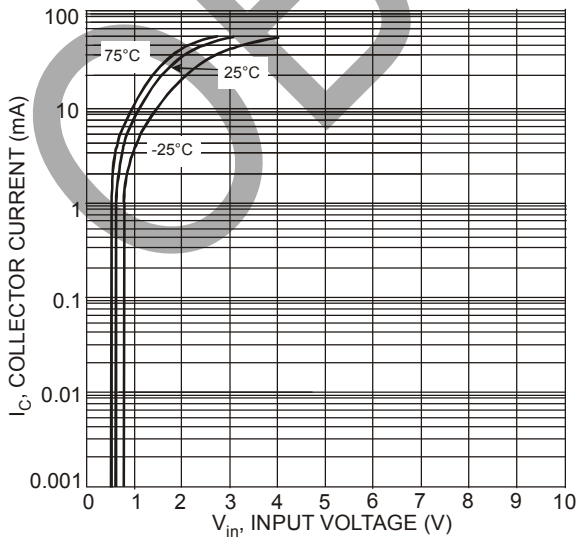


Fig. 5 Collector Current vs. Input Voltage

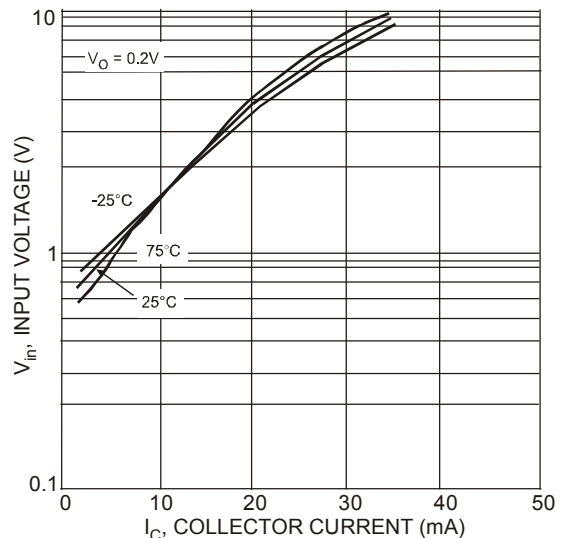


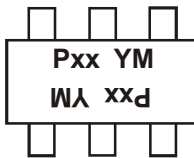
Fig. 6 Input Voltage vs. Collector Current

Ordering Information (Notes 4 & 5)

Part Number	Case	Packaging
DDA124EK-7	SOT-26	3000/Tape & Reel
DDA144EK-7	SOT-26	3000/Tape & Reel
DDA114YK-7	SOT-26	3000/Tape & Reel
DDA123JK-7	SOT-26	3000/Tape & Reel
DDA114EK-7	SOT-26	3000/Tape & Reel
DDA143TK-7	SOT-26	3000/Tape & Reel
DDA114TK-7	SOT-26	3000/Tape & Reel

- Notes:
- For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.
 - For Lead Free/ROHS Compliant version part numbers, please add "-F" suffix to the part numbers above. Example: DDA114TK-7-F.

Marking Information



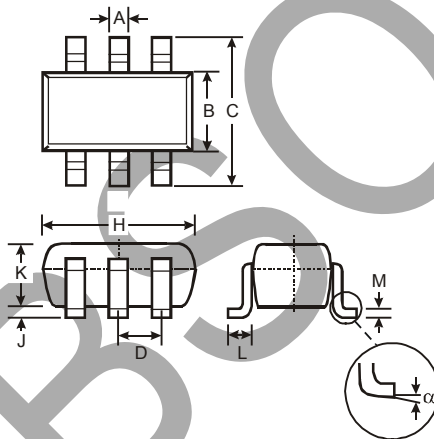
Pxx = Product Type Marking Code (See Page 1)
 YM = Date Code Marking
 Y = Year (ex: T = 2006)
 M = Month (ex: 9 = September)

Date Code Key

Year	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015
Code	T	U	V	W	X	Y	Z	A	B	C

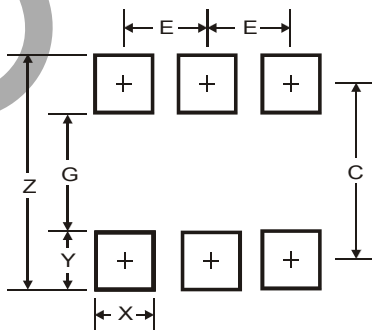
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Package Outline Dimensions



SOT-26			
Dim	Min	Max	Typ
A	0.35	0.50	0.38
B	1.50	1.70	1.60
C	2.70	3.00	2.80
D	—	—	0.95
H	2.90	3.10	3.00
J	0.013	0.10	0.05
K	1.00	1.30	1.10
L	0.35	0.55	0.40
M	0.10	0.20	0.15
α	0°	8°	—
All Dimensions in mm			

Suggested Pad Layout



Dimensions	Value (in mm)
Z	3.20
G	1.60
X	0.55
Y	0.80
C	2.40
E	0.95

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